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Data Sheet

October 2013

N-Channel Logic Level Power MOSFET 50 V, 14 A, 100 mΩ

These are N-channel power MOSFETs manufactured using the MegaFET process. This process, which uses feature sizes approaching those of LSI integrated circuits, gives optimum utilization of silicon, resulting in outstanding performance. They were designed for use in applications such as switching regulators, switching converters, motor drivers and relay drivers. This performance is accomplished through a special gate oxide design which provides full rated conductance at gate bias in the 3V-5V range, thereby facilitating true on-off power control directly from logic level (5V) integrated circuits.

Formerly developmental type TA09870.

Ordering Information

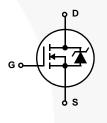
PART NUMBER	PACKAGE	BRAND
RFD14N05L	TO-251AA	14N05L
RFD14N05LSM	TO-252AA	14N05L
RFD14N05LSM9A	TO-252AA	14N05L

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252AA variant in the tape and reel, i.e., RFD14N05LSM9A.

Features

- 14A, 50V
- r_{DS(ON)} = 0.100Ω
- Temperature Compensating PSPICE[®] Model
- Can be Driven Directly from CMOS, NMOS, and TTL Circuits
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- 175^oC Operating Temperature
- Related Literature
 - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

Symbol



JEDEC TO-251AA JEDEC TO-252AA

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RFD14N05L, RFD14N05LSM, RFD14N05LSM9A	UNITS
Drain to Source Voltage (Note 1)V _{DSS}	50	V
Drain to Gate Voltage (R _{GS} = 20kΩ) (Note 1) V _{DGR}	50	V
Gate to Source Voltage	±10	V
Continuous Drain Current	14	А
Pulsed Drain Current (Note 3)	Refer to Peak Current Curve	
Pulsed Avalanche Rating	Refer to UIS Curve	
Power Dissipation	48	W
Derate above 25 ^o C	0.32	W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10s TL	300	°C
Package Body for 10s, See Techbrief 334	260	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN	TYP	MAX	UNITS
Drain to Source Breakdown Voltage	BV _{DSS}	I _D = 250μA, V _{GS} = 0V, Figure 13		50	-	-	V
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 250\mu$ A, Figure12		1	-	2	V
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 40V, V_{GS} = 0V$		-	-	1	μA
		$V_{DS} = 40V, V_{GS} = 0V, T_{C} = 150^{\circ}C$		-	-	50	μA
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 10V$		-	-	±100	nA
Drain to Source On Resistance (Note 2)	r _{DS(ON)}	I _D = 14A, V _{GS} = 5V,	Figures 9, 11	-	-	0.100	Ω
Turn-On Time	t(ON)	V _{DD} = 25V, I _D = 7A,		-	-	60	ns
Turn-On Delay Time	t _{d(ON)}	$R_{L} = 3.57\Omega, V_{GS} = 5V,$ $R_{GS} = 0.6\Omega$		-	13	-	ns
Rise Time	tr			-	24	-	ns
Turn-Off Delay Time	t _{d(OFF)}			-	42	-	ns
Fall Time	t _f			-	16	-	ns
Turn-Off Time	t(OFF)			-	-	100	ns
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to $10V$	$V_{DD} = 40V, I_D = 14A,$	-	-	40	nC
Gate Charge at 5V	Q _{g(5)}	$V_{GS} = 0V$ to 5V	R _L = 2.86Ω — Figures 20, 21	-	-	25	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V$ to 1V		-	-	1.5	nC
Input Capacitance	C _{ISS}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz Figure 14		-	670	-	pF
Output Capacitance	C _{OSS}			-	185	-	pF
Reverse Transfer Capacitance	C _{RSS}			-	50	-	pF
Thermal Resistance Junction to Case	R _{θJC}			-	-	3.125	°C/W
Thermal Resistance Junction to Ambient	R _{θJA}	TO-251		-	-	100	°C/W
	R _{0JA}	TO-252		<u> </u>		100	°C/W

Source to Drain Diode Specifications

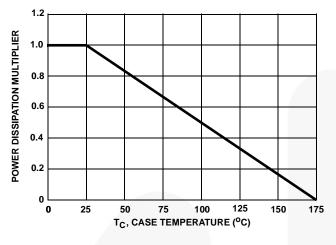
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Source to Drain Diode Voltage (Note 2)	V _{SD}	I _{SD} = 14A	-	-	1.5	V
Diode Reverse Recovery Time	t _{rr}	I_{SD} = 14A, dI _{SD} /dt = 100A/µs	-	-	125	ns

NOTES:

2. Pulse Test: Pulse Width ≤300ms, Duty Cycle ≤2%.

3. Repetitive Rating: Pulse Width limited by max junction temperature. See Transient Thermal Impedance Curve (Figure 3) and Peak Current Capability Curve (Figure 5).

Typical Performance Curves Unless Otherwise Specified





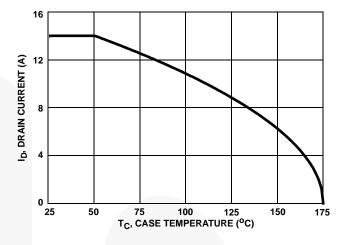
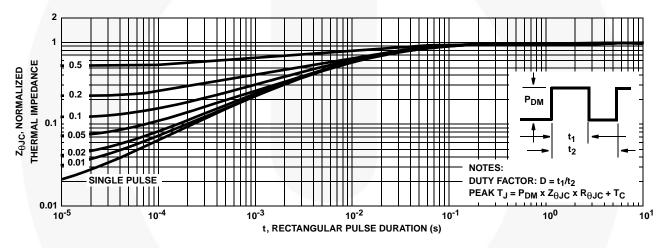
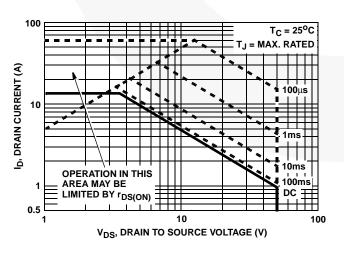


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs TEMPERATURE









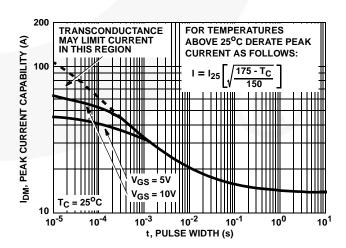
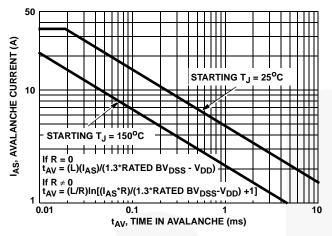


FIGURE 5. PEAK CURRENT CAPABILITY

Typical Performance Curves Unless Otherwise Specified (Continued)





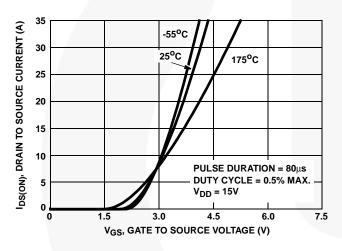


FIGURE 8. TRANSFER CHARACTERISTICS

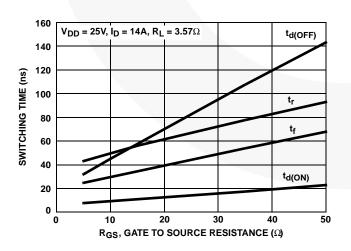
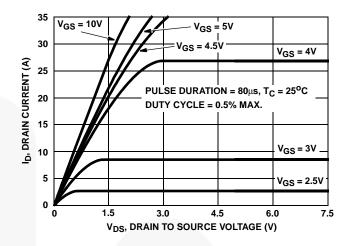
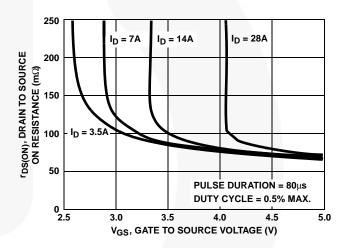


FIGURE 10. SWITCHING TIME vs GATE RESISTANCE









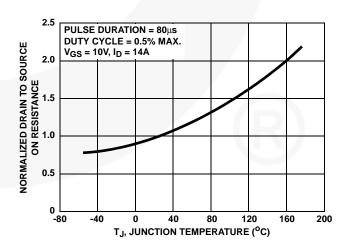
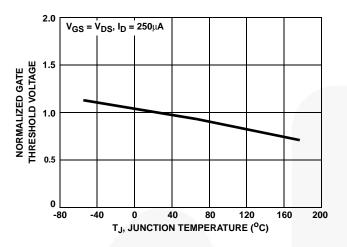


FIGURE 11. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

Typical Performance Curves Unless Otherwise Specified (Continued)





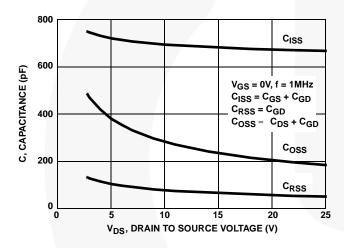


FIGURE 14. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

Test Circuits and Waveforms

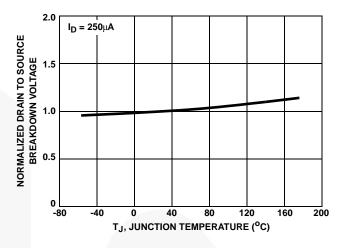
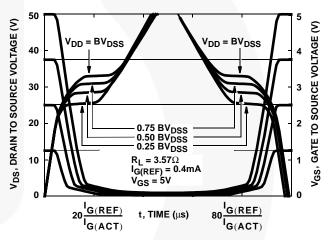


FIGURE 13. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260, FIGURE 15. TRANSCONDUCTANCE vs DRAIN CURRENT

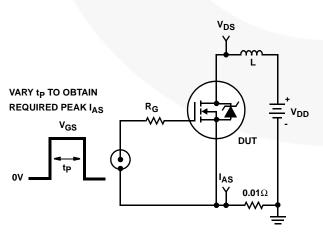


FIGURE 16. UNCLAMPED ENERGY TEST CIRCUIT



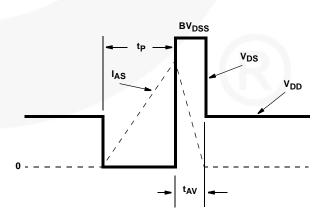


FIGURE 17. UNCLAMPED ENERGY WAVEFORMS

Test Circuits and Waveforms (Continued)

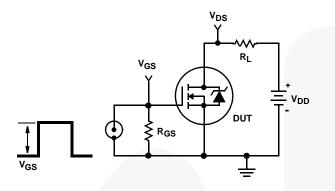


FIGURE 18. SWITCHING TIME TEST CIRCUIT

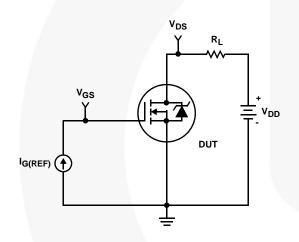


FIGURE 20. GATE CHARGE TEST CIRCUIT

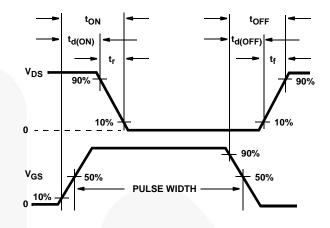


FIGURE 19. RESISTIVE SWITCHING WAVEFORMS

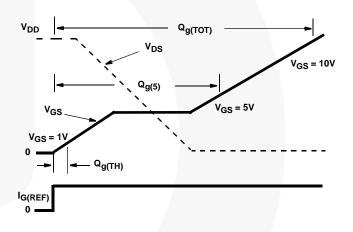
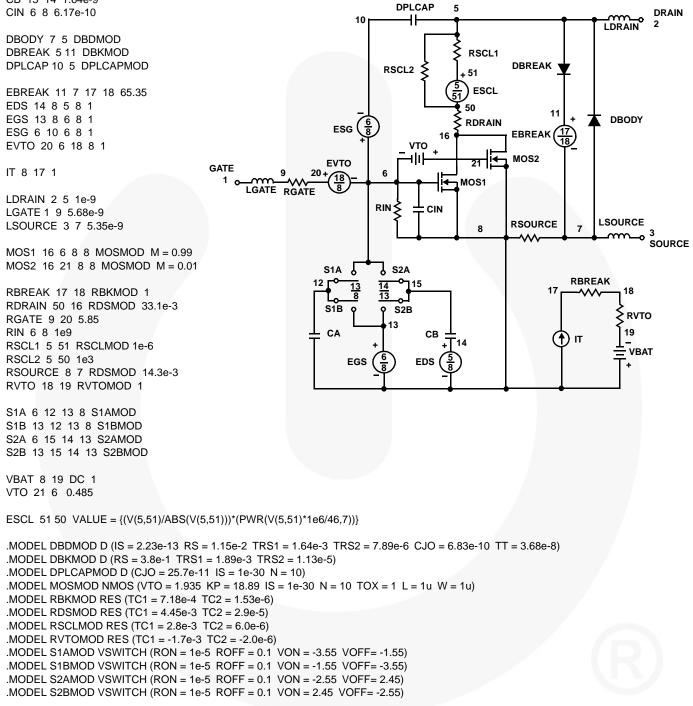


FIGURE 21. GATE CHARGE WAVEFORMS

PSPICE Electrical Model

.SUBCKT RFP14N05L 2 1 3; rev 9/15/94

CA 12 8 1.464e-9 CB 15 14 1.64e-9 CIN 6 8 6.17e-10



.ENDS

NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-circuit for the Power MOSFET Featuring Global Temperature Options**; authored by William J. Hepp and C. Frank Wheatley.



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